

As a below named inv	ventor, I hereby declare that	at:	
My residence, post of	fice address and citizensh	ip are as stated below next to n	пу пате,
first and joint inventor and for which a paten VOLTAGE, LOW POV specification of which	(if plural names are listed t is sought on the invention NER AND HIGH PERFOR is attached hereto unless	r (if only one name is listed below) of the subject matter who entitled A SIMULATED CIRCUMANCE TYPE II CURRENT Countries the following box is checked:	nich is claimed UIT LAYOUT FOR LOW ONVEYOR , the
hereby state that I have		ates Application Number 09/820 and the contents of the above in diment referred to above.	
I acknowledge the dut 1.56.	ty to disclose information v	vhich is material to patentability	as defined in 37 CFR §
application(s) for pate designated at least o below by checking	ent or inventor's certificate, one country other than the the box, any foreign ap on having a filing date befo	r 35 U.S.C. §119(a)-(d) or § , or § 365(a) of any PCT Interne United States, listed below plication for patent or inventore that of the application on wh	ational application which and have also identified or's certificate, or PCT
 .			
(Number)	(Country)	(Day/Month/Year Filed)	
			
(Number)	(Country)	(Day/Month/Year Filed)	
I hereby claim the be listed below.	enefit under 35 U.S.C. §	119(e) of any United States p	provisional application(s)
 (Application Number)	—— (Filing Date)		JAN 0 9 2003
(Application Number) (Application Number)	(Filing Date) (Filing Date)	COPY	Technology Center 2100
		20 of any United States applica United States, listed below and	

I hereby claim the benefit under 35 U.S.C. § 120 of any United States application(s), or 365(c) of any PCT International application designating the United States, listed below and, insofar as the subject matter of each of the claims of this application is not disclosed in the prior United States or PCT International application in the manner provided by the first paragraph of 35 U.S.C. § 112, I acknowledge the duty to disclose information which is material to patentability as defined in 37 CFR § 1.56 which became available between the filing date of the prior application and the national or PCT international filing date of this application: